AXEL

-A Xenon Electro Luminescence detector -High Density Xenon gas TPC for double beta decay search and direction sensitive dark matter search • References are from "Noble Gas Detectors" unless otherwise noted.

Double Beta decay candidates

	abound(%)	τ(2νββ) yr	Q(keV)	Q ⁵ /1E16	Q ⁵ xτ(2νββ)/1E36	
48Ca	0.187	3.9E+19	4271	142.12	55.4	enrichment difficult
76Ge	7.8	1.7E+21	2039	3.52	59.9	
82Se	9.2	9.6E+19	2995	24.10	23.1	
96Zr	2.8	2.0E+19	3350	42.19	8.4	
100Mo	9.6	7.1E+18	3034	25.71	1.8	
110Pd	11.8		2013	3.31		
116Cd	7.5	2.8E+19	2802	17.27	4.8	
124Sn	5.64		2228	5.49		
130Te	34.5	7.6E+20	2529	10.35	78.6	
136Xe	8.9	2.2E+21	2479	9.36	208.8	
150Nd	5.6	9.2E+18	3367	43.27	4.0	enrichment difficult

* $\tau(2\nu\beta\beta) \propto Q^{11}$, $\tau(0\nu\beta\beta) \propto Q^5$

¹³⁶Xe

- Xenon production rate
 - 5000-7000m³/yr ~50ton in 1998.
- \geq 2x10⁶ kton exists in air
- > Enrichment is relatively easy.

	Density at 0°C,1atm (g/L)	Liquid Density (g/cm3)	Melting point(K)	Boiling point(K)
He	0.1786	0.145	-	4.22
Ne	0.9002	1.2	24.56	27.07
Ar	1.784	1.398	88.80	87.30
Kr	3.749	2.413	115.79	119.93
Xe	5.894	3.053	161.4	165.03

Energy resolution

- Statistical limit
 - W-value 21.5 eV, Fano factor<0.17
 - → 0.29%(FWHM)@2.48MeV (0.55%(FWHM)@662keV)
- At higher density, energy resolution becomes worse. \rightarrow reject liquid option.

A. Bolotnikov, B. Ramsey / Nucl. Instr. and Meth. in Phys. Res. A 396 (1997) 360-370



Fig. 5. Density dependencies of the intrinsic energy resolution (%FWHM) measured for 662 keV gamma-rays.

High density (15~30 x STP)

High pressure

- Need pressure vessel including feed through
- Need photo detector operatable at high pressure

我々のBaseline design(目標)

- 1 ton enriched ¹³⁶Xe gas (not liquid)
- At 15~30 times higher density than STP
 - $\rho = 0.088^{\circ}0.18g/cm^{3}$
- Use proportional scintillation mode (Electroluminescence) for energy measurement
 - Energy resolution goal < 0.5%(FWHM)</p>
 - Ultraviolet photon(~170n) detection by MPPC
- Tracking as TPC
 - Range(2.5MeV e) ~ 210 cm at STP
 - T_0 by primary scintillation signal
 - Sample 15~20 points using pads. 5~7.5mm spacing \rightarrow 5.5x10⁴~1.2x10⁵ ch
 - Purpose is to identify two blobs at track ends. \rightarrow distinguish from α 's and γ 's.
 - Electric field for drift : ~1.5kV/cm@30bar \rightarrow drift velocity ~1m/ms
- Energy measurement by ELCC(see next pages)







Milestones

 MPPC 64チャンネル、10気圧検出器を製作し 1.3MeVガンマ線の測定で原理証明 - このための開発要素、盛りだくさん。 • 来年度以降の目標は - キセノン10気圧 9kg検出器 - 30気圧 27kg検出器で世界記録更新 \checkmark

- 30気圧1トン検出器で発見!

Scintillation



Fig. 3.38 Dependence of light output of scintillations excited by alpha particles on the density of high-pressure xenon: open squares represent data of Bolotnikov and Ramsey [33], closed circles represent data of Kobayashi et al. [198]. Redrawn from [198].

6. Impurity emission. Any impurity molecules present may quench the emission of hard UV light, and their own emission may be stimulated by transfer of excitation energy. This is of practical importance in the xenon, which is used as a wavelength-shifter the emission from helium or argon, which excitation energies are higher than the minimum xenon excitation level. At relative concentration of 10⁻⁵, nitrogen is adequate for efficient energy transfer from all the noble gases at atmospheric pressure. At relative concentration of 10⁻³, Xe can be used as a wavelength shifter, for example in ³He scintillator at 3.5 MPa pressure [171]. Sometimes, impurities have nonradiative transitions or emit in regions where the sensitivity of photodetectors is limited. This effect may dramatically reduce the observed light yield of noble gases scintillators.



Fig. 3.27 Noble gas continua of helium, argon, krypton, and xenon normalized to the same intensity of the maximum. Redrawn from [176].

What is the influence on scintillation from N₂ or H₂ addition?

Electric Field and electron drift



simulation example 1

initial ionization distribution

after 1m drift



Electroluminescence



Fig. 6.2 Amplification process in gas detectors with gas gain (a) and electroluminescence (b) or proportional scintillation.

Good and stable linearity are expected because

• A linear amplification process.

c.f. Electron multiplication process is exponential process.

- The number of produced photons is proportional to the voltage drop rather than to the field strength.
 - Insensitive to the capacitance change by microphonic vibration
- To keep original resolution determined by career generation,
 - ϵ Y>1/F (ϵ >5% for 400 photons/e)
 - c.f. usually <1%

In a uniform electric field, the number of photons generated by one drifting electron $N_{\rm ph}$, is proportional to the drift path x [cm] and for xenon gas at room temperature may be defined via the reduced electric field strength E/p [kV cm⁻¹ bar⁻¹] and the gas pressure p [bar] using the empirical equation [144] as

 $dN_{ph}/dx = 70(E/p - 1.0)p$ (UV photons/e cm drift) (3.24)

The intensity of electroluminescence (EL) up to 1700 photons/cm in xenon at 0.5 MPa pressure has been demonstrated [144]. Taking into account that the energy of a single photon of 172 nm wavelength is about 8.4 eV, one can calculate the efficiency of conversion of the energy of the electric field into the photon emission: $\xi = (1700 \times 8.4)/(3400 \times 5) = 84\%$. The rest of the energy ac-

w/ 5 mm gap
To get 200 (400) photons, 18 (21) kV@30atm.
7.9 (11) kV@10atm.
3.4 (6.2) kV@1atm.

w/ 4 mm gap
To get 200 (400) photons,
4.9 (7.7) kV@5atm.
3.3(6.1) kV@1atm.



Fig. 3.17 Reduced light output of electroluminescence of xenon gas at 293 K temperature and normal pressure as a function of the reduced electric field strength (compilation of experimental and computer simulation data by Conde [143]).

Readout by Electroluminescence light collection cell (ELCC)



Electric Field in ELCC



geant4?)

10気圧の場合。 アノードの穴はφ4。 PTFEの穴はφ5。 anodeは10.5kV ドリフト電場は 500V/cm



ELCC light collection efficiency

- by Geant4. cell内で光を一様発生
- PTFEについては、波長175nm以下での反射が観測されていない。175nm以上では反射率は>55%とされているので、平均反射率として11%を仮定。
- 収集効率は12.9% (これに、光検出器のefficiencyを掛ける必要あり。)
- ギャップを長くすれば、EL gainは十分に稼げるが、電圧 は高くなる。wavelength shifterを塗って可視光にしてし まう手もある。どちらが良いかは、詳細に検討しないと わからない。



MPPCに対する要求

EL光

- 全光量は~1e6 photons.(ELで10倍増幅した 場合)
- MPPC1個での瞬間最大光量は 1e3phtons/50ns
- 3mm角、ピクセルピッチ10µm(ピクセル数 9e4)からピクセルピッチ25µm(ピクセル数 1.4e4)のMPPC
- 保護膜なしのタイプで紫外光を直接検出するか、WLSで可視光に変換するか。



Fig. 3.27 Noble gas continua of helium, argon, krypton, and xenon normalized to the same intensity of the maximum. Redrawn from [176].

"Noble Gas Detectors"より [176] R.E.Huffman, J.C.Larrabee and Y.Tanaka, Appl. Opt. 4, 1581-1588 (1965)

光収集セル(ELCC)の構造

電極1と電極2の間に高電圧がかかる。
 電極2はGND



MPPC plane



プラスチックの板に両方向 中継ソケットを差し込む。 ソケットの表側にMPPC、片 側にケーブルを圧着したピ ンを差し込む。 PTFEだと、MPPCを抜くとき に、ソケットが板から抜けて しまった。

primary scintillation to determine t₀

- 全光量
 - Ws = 76eV (from NEXT CDR) \rightarrow 32,300 photons
- Tracking planeでのlight yield
 - 2m\u00f6x1.7mHの円柱で両側にtracking planeがあると仮定 → planeの acceptance 17.5%x2
 - ELCC開口率
 - 2mmø, 5mm spacingだと12.6%
 - PDE 20%と仮定
 - 32,300*0.175*2*0.126 *0.2 = 284 p.e.
 - ELCCの開口穴半径を3mmφにすると、639p.e.
- これを全MPPC(>1e5 ch)の和として検出するのは難しい。(dark currentと区別がつかない)
- 低温にしてMPPCのdark rateを下げるか高圧化で動作するPMTが 必要。

Wavelength shifter

	Pressure (MPa), size(cm)	WLS	Particle, Energy(MeV)	En. Res., % FWHM	Ref.
⁴ He	13.8; 5 I.D.×8.6	7%Xe, DPS	n, 1.0	36	[234]
Ne	1.7	20%Xe	n, 3.5	6.7	[231]
³ He	2.0	10%Xe	n, < 3	14	[232]
	3.5; 1.7×0.5	0.5%Xe, p-TP	n _{th}	18	[171]
	24.8; 38 cm ³	DPS	n _{th}	54	[233]
			α, 5.15	16	
	20.0; 4 I.D.×4	5%Xe, p-TP	n, 2.5	4.8	[236]
	13.8; 5 I.D.×8.6	2%Xe, DPS	ռ _{եհ}	31	[235]
Xe	2.8	25%N ₂	n, 0.5	29.5	[231]

Tab. 4.1 High-pressure noble gas scintillation detectors.

Note: WLS - wavelength shifting; DPS - trans p,p'-diphenylstilbene; p-TP - paraterphenyl; n_{th} - thermal neutrons.

- Acrylic tube coated with a thin layer of polysterene doped with organic fluor TPB (tetraphenyl butadiene) (p.114)
- N₂ output peak 340nm

8.5.2.1 Wavelength Shifters Dissolved in Noble Gases

One of the first wavelength shifters used with noble gas scintillators was a gas admixture of nitrogen. For example, Grün and Schopper [228] used argon in mixture with 2% of nitrogen in their development of a detector for triggering of cloud chambers. The addition of a small amount of nitrogen to noble gases enhances the light emission in the blue range. At earlier studies it was concluded that nitrogen acts as a simple fluorescent converter. However, the nitrogen also acts as the quenching agent: its addition to the noble gas results in decreasing the absolute scintillation efficiency. For example, Northrop and Nobles [13] observed that there is a reduction in the practical light output of a xenon gas scintillator, used with solid wavelength shifter, when nitrogen is added. The efficiency is reduced by about 1/3 by addition of 10% of nitrogen or hydrogen. The latter is often used in high-pressure xenon detectors to increase the drift velocity of electrons. Another undesirable feature of nitrogen is the introduction of a slower component of decay time. For example, the addition of 10⁻⁴ N₂ introduces in argon scintillator a component with decay time of 0.5 µs, which accounts for 75% of the total photon emission [170]; the decay time reduces with an increase in the concentration of nitrogen, however, this reduces the total light yield. From all these facts, one can conclude

8.5.2.2 Solid Wavelength Shifters

A number of solid wavelength shifters deposited onto optical elements such as windows and mirrors have been considered including *trans*-stilbene, tetraphenylbutadiene (TPB), sodium salicylate, p-quaterphenyl, diphenylstilbene, and p-terphenyl (see, for example, McKinsey et al. [429] and references therein). The last one was found to be the best one to be used with xenon and xenon-containing gas mixtures from the point of view of high quantum efficiency (> 90% according to Belogurov et al. [144]), low hydroscopic, chemical inertness, and exclusive radiation hardness. Emission and absorption spectra of p-terphenyl are presented in Fig. 8.10.



Fig. 8.10 (a) Absorption and (b) emission spectra of p-terphenyl [407].

The p-terphenyl is reported to have a short decay time of 2–5 ns and widely used as a scintillating dye in plastic scintillators. Kumar and Datta [430] com-

Wavelength shifter –p-terphenly



Fig. 1. Absorption and emission spectra of *p*-terphenyl. 1 – *p*-terphenyl in solvent, absorption, 2 – polycrystalline *p*-terphenyl, absorption, 3 – *p*-terphenyl in solvent, emission, 4 – polycrystalline *p*-terphenyl, emission.

D.Yu.Akimov et. al, "Development of VUV wavelength shifter for the use with a visible light photodetector in noble gas filled detectors" http://dx.doi.org/10.1016/j.nima.2011.12.036

D.Yu. Akimov, et al., Nucl. Instr. & Meth. A (2011), doi:10.1016/j.nima.2011.12.036

A *p*-terphenyl is known to be a quite <u>volatile</u> organic substance. The use of it is seriously problematic in the liquid noble gas detectors with charge collection, especially in the liquid xenon ones, because it dramatically reduces the lifetime of free electrons created by an ionising particle. To avoid contamination of the liquid xenon by the *p*-terphenyl molecules are coated the WLS with a $\sim 1 \,\mu m$ poly-para-xylylene protection film. Poly-para-xylylene (Parylene N) [16] is chosen due to its well known properties such as the very low permeability to gases, and the possibility to form a conformal optically transparent film practically free of pin-holes even for the thicknesses down to several tens Å. Since the polypara-xylylene is not transparent for the UV light, the *p*-terphenyl is deposited to the 1- mm thick sapphire, which is situated the first on the way of the UV light. The photodetector then to be situated

TPB (tetraphenyl butadiene) coating

- <u>http://microboone-docdb.fnal.gov/cgi-bin/ShowDocument?docid=1006</u>
- "Environmental Effects on TPB Wavelength-Shifting Coatings", C.S. Chiu et.al, JINST 7 (2012) P07007
 - a TPB solution consisting of a 1:1:43 ratio by mass of PS to TPB to toluene. Each acrylic plate required three coatings of the TPB solution. This has been measured to have about 50% of the efficiency of the evaporative coating.
 - the harmful effect of certain wavelengths of light on the degradation of 50% TPB-PS chemical TPB coatings and isolated the most damaging wavelength range to the UV spectrum. On the other hand, we have seen that humidity does not play a significant role in long run plate degradation.
- Additional info. From the top document
 - Above 33%, the TPB will crystallize out of solution.
 - Adding ethanol to this mixture breaks up the surface tension, making the coating look smooth and uniform
 - Plates are wiped after coating to remove any loose TPB, after which they do not degrade further and are very resilient

simulation example 1 row track



simulation example 1 diffusion after 1m drift





simulation example 1 segmentation (7.5mm in x or y and 2mm in z)



-20 -10 0 10 20 30

40 50

X(mm)

z marginalized by ELCC generation time(4µs)

simulation example 2 row track



simulation example 2 diffusion after 1m drift





simulation example 2 segmentation (7.5mm in x or y and 2mm in z)



z marginalized by ELCC generation time(4µs)

2.5MeV electron example1

row track

detected track



2.5MeV electron example2

(mu)z 30

20

row track







detected track

од ар 500ш

400

300

200

100

X(mm)







2.5MeV alpha example

row track

detected track





note that scale is very different from electron cases.

trackイメージにより

- α backgroundは良く落とせそう
- γ backgroundで、ちょうど2.5MeVで光電吸収 したような事象は、すべて落とすことは難しい (コンプトン散乱等、複数の場所で電子を出すような 事象は、落とせる)

Back ground



図6 ウラン 238 とトリウム 232 の崩壊系列

[出典]W. マーシャル(編)・加藤和明(監訳):放射線とその応用-上、筑摩書房(1987.7)、p36

Radioactive contaminants in detector materials

After the decay of ²¹⁴Bi, the daughter isotope, ²¹⁴Po, emits a number of de-excitation gammas with energies above 2.3 MeV. The gamma line at 2447 keV, of intensity 1.57%, is very close to the Q-value of ¹³⁶Xe. The gamma lines above $Q_{\beta\beta}$ have low intensity and their contribution is negligible.

The daughter of ²⁰⁸Tl, ²⁰⁸Pb, emits a de-excitation photon of 2614 keV with a 100% intensity. The Compton edge of this gamma is at 2382 keV, well below $Q_{\beta\beta}$. However, the scattered gamma can interact and produce other electron tracks close enough to the initial Compton electron so they are reconstructed as a single object falling in the energy region of interest (ROI). Photoelectric electrons are produced above the ROI but can loose energy via bremsstrahlung and populate the window, in case the emitted photons escape out of the detector. Pair-creation events are not able to produce single-track events in the ROI.

Radon

Radon constitutes a dangerous source of background due to the radioactive isotopes ²²²Rn (half-life of 3.8 d) from the ²³⁸U chain and ²²⁰Rn (half-life of 55 s) from the ²³²Th chain. As a gas, it diffuses into the air and can enter the detector. ²¹⁴Bi is a decay product of ²²²Rn, and ²⁰⁸Tl a decay product of ²²⁰Rn. In both cases, radon undergoes an alpha decay into polonium, producing a positively charged ion which is drifted towards the cathode by the electric field of the TPC. As a consequence, ²¹⁴Bi and ²⁰⁸Tl contaminations can be assumed to be deposited on the cathode surface. Radon may be eliminated from the TPC gas mixture by recirculation through appropriate filters. There are also ways to suppress radon in the volume defined by the shielding. Radon control is a major task for a $\beta\beta0\nu$ experiment, and will be of uppermost importance for NEXT-100.

J.J.Gomez-Cadenas et.al, "Present status and future perspectives of the NEXT experiment", arXiv:1307.3914

ELCC ver0



ELCC ver0 読み出しには 1 inch PMTにwave length shifter(TPB) を塗布して使用



EL信号観測に成功!

光量が少ないため、PMTのパルス (~20ns)が重なって針のような信号 に見えている。



ELCCでの放電



フィードスルーでの放電

- 問題点
 - フィードスルー、ELCCのギャップ間で放電
 - 低電圧運用(ELCCのギャップ4mmで3kV)、電子の収集効率が悪いことに よる光量不足
 - → ver1で改善へ

ELCC ver1

• 読み出しにはUVPMT(浜ホトH3178)を用いた。



フィールドケージ



28 × 28 × 55mm

FEMMによる電場計算

ELCC信号例

- 読み出しには100MHz FADC(CAEN V1724)を使用
- フィールドケージ内での電離電子のZ方向の広がり(~1cm)に対して、ドリフト速度が~1×10⁵cm/sなので、信号幅は~10μs程度と予想される。



光量分布

- 2個のピークが見られる。-> 60keVピークとエスケープピーク(後述)
- 低値側に裾を引いているのはELCCの有効領域から漏れ出した電子の信号が失われたからであると考えられる。
- ピークの右側だけを用いてFWHMを概算評価した。



Ver.3

- 1 MPa chamber
 - JIS配管
 - ガスケットにu-tightsealを採用 (helicoflexと同じようなメタルシール)
 - –フィードスルーは、テフロンケーブルをエポキシ モールド (TECSAM)
- MPPC plane (up to 64 channel)
- under construction



Xeの純度

- PMT、ELCCからのアウトガス、フィードスルーのついたフランジからのリークにより、Xeの純度が悪化している可能性がある。
- 純度悪化による光量の減少
 電離電子の不純物ガスへの付着
 Xe励起状態のクエンチ
 Xe₂* + M -> 2Xe + M
- 純度モニターの手法
 Xe不純物によるdrift速度の変化(ELCC信号時間幅)を使う?

Gas purification

MEG prototype

ameter) tungsten wires suspended inside the detector volume. Xenon is continuously evaporated, passed through an Oxisorb cartridge, a molecular sieve and a hot metal getter and condensed back in the detector. During several weeks of operation, the absorption length of scintillation light was increasing and has reached >150 cm in four weeks. Mass-spectrometric analysis has shown the presence of water as a dominant impurity in xenon. Monte Carlo

高圧のキセノンを循環できるか? 純度を保つためには、金属ベローズポン プか。ただし、高圧のものがなかなか見つからない。循環させなくても、 ゲッターやモレキュラーシーブをつないでおくだけではダメか?

ガスの再利用

- キセノンが高いので、液体窒素で再収集する
 ことを考えている。
- が、常温に戻したときに10気圧以上になると 高圧ガス製造装置になる可能性があり、ずっ と冷やしていないといけない。。。。
- お金があれば、冷凍庫を買う? チェンバー
 をもう1個買う方が安いか。



圧力計:圧力範囲は-1気圧から12気圧 バルブ:V-V1のみ流量調整(ベローズ)。その他は開閉(ダイヤフラム)。

HV power supply

- 高電圧を容器の外からかけると、フィードスルーの耐圧が問題になるため、液体 Arではコッククロフトウォルトン電源が検討されている。
 - 測定中は、AC入力を切る。電圧のモニターができない。Liq Arではノイズが問題だがEL
 読み出しでもだめか?
- 10気圧プロトタイプ
 - ドリフト電場 500V/cm
 - フィールドゲージはv2と同じ(ギャップ5.5mmx10段) → 275V/gap x 10段
 - EL電場 7.9~11kV @ 5mmギャップ
 - total max 13.75kV
 - これならば、コッククロフトウオルトンではなく、15kV耐圧のフィードスルーを2個使うべき。(+抵抗分割)
- 30気圧本番
 - ELCC電場 21kVまたはもっと。



ELTR-30K2型 DC30kV重畳用の高耐圧絶縁トランスです。 小型ION源重畳用です。

電圧	:	1¢ 100:100 50∕60Hz
耐電圧	1	WV DC30kV
容量	1	300VA
入力線	2	3Pプラグ線 3m 1本
出力線	1	DC30kVシリコン線
出力部	-	2連3PACコンセント 2個

Direction sensitive dark matter search

- Extend the idea by D.R.Nygren, "Columnar recombination: a tool for nuclear recoil directional sensitivity in a xenon-based direct detection WIMP search"
- Our plan is to investigate the possibility of operation under magnetic field. → Enhance the recombination for the track parallel to the field
- To keep O(eV) electron curvature < O(10)μm, hi field (>1T) is necessary